Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type  $(\pi - MOSVII)$ 

# TK5A60D

#### **Switching Regulator Applications**

• Low drain-source ON-resistance: RDS (ON) = 1.2  $\Omega$  (typ.)

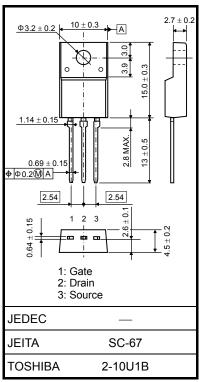
• High forward transfer admittance:  $|Y_{fs}| = 3.0 \text{ S (typ.)}$ 

• Low leakage current:  $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 600 \text{ V)}$ 

• Enhancement-mode:  $V_{th} = 2.4 \text{ to } 4.4 \text{ V (VDS} = 10 \text{ V, ID} = 1 \text{ mA)}$ 

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	600	V
Gate-source voltage		$V_{GSS}$	±30	V
Drain current	DC (Note 1)	I <sub>D</sub>	5	
	Pulse (t = 1 ms) (Note 1)	I <sub>DP</sub>	20	Α
Drain power dissipati	on (Tc = 25°C)	P <sub>D</sub>	35	W
Single pulse avalanch	ne energy (Note 2)	E <sub>AS</sub>	189	mJ
Avalanche current		I <sub>AR</sub>	5	Α
Repetitive avalanche energy (Note 3)		E <sub>AR</sub>	3.5	mJ
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C



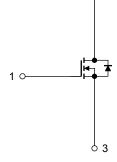
Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R <sub>th (ch-c)</sub>	3.57	°C/W
Thermal resistance, channel to ambient	R <sub>th (ch-a)</sub>	62.5	°C/W

**Internal Connection** 



Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Note 2:  $V_{DD}$  = 90 V,  $T_{ch}$  = 25°C (initial), L = 13.2 mH,  $R_G$  = 25  $\Omega$ ,  $I_{AR}$  = 5 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.

Start of commercial production 2009-07

**Q** 2

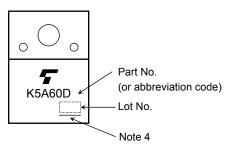
#### **Electrical Characteristics (Ta = 25°C)**

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μA
Drain cut-off current		I <sub>DSS</sub>	V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V	_	_	10	μA
Drain-source breakdown voltage		V (BR) DSS	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	600	_	_	V
Gate threshold voltage		V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.4	_	4.4	V
Drain-source ON-resistance		R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 2.5 A	_	1.2	1.43	Ω
Forward transfer admittance		Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 2.5 A	0.8	3.0	_	S
Input capacitance		C <sub>iss</sub>		_	700	_	
Reverse transfer capacitance		C <sub>rss</sub>	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	4	_	pF
Output capacitance		Coss		_	80	_	
Switching time	Rise time	t <sub>r</sub>	$\begin{array}{c c} 10 \text{ V} & \text{I}_D = 2.5 \text{ A} & \text{Vout} \\ \hline \text{VGS} & \text{V} & \text{VOD} \\ \hline 50  \Omega & \text{VOD} \approx 200 \text{ V} \\ \hline \text{Duty} \leq 1\%,  t_\text{W} = 10  \mu\text{s} \\ \end{array}$		20	_	
	Turn-on time	t <sub>on</sub>			40	_	ns
	Fall time	t <sub>f</sub>			11		
	Turn-off time	t <sub>off</sub>		_	60	_	
Total gate charge		Qg		_	16	_	
Gate-source charge		Q <sub>gs</sub>	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 5 \text{ A}$	_	10	_	nC
Gate-drain charge		Q <sub>gd</sub>			6	_	

### **Source-Drain Ratings and Characteristics (Ta = 25°C)**

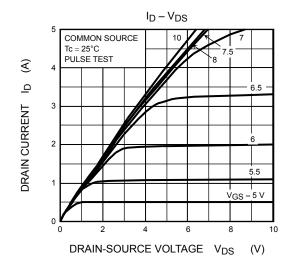
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I <sub>DR</sub>	_	_	_	5	Α
Pulse drain reverse current (Note 1)	I <sub>DRP</sub>	_	_	_	20	Α
Forward voltage (diode)	V <sub>DSF</sub>	$I_{DR} = 5 A$ , $V_{GS} = 0 V$			-1.7	٧
Reverse recovery time	t <sub>rr</sub>	$I_{DR} = 5 \text{ A}, V_{GS} = 0 \text{ V},$	_	1200	_	ns
Reverse recovery charge	Q <sub>rr</sub>	dl <sub>DR</sub> /dt = 100 A/μs		7.2	_	μC

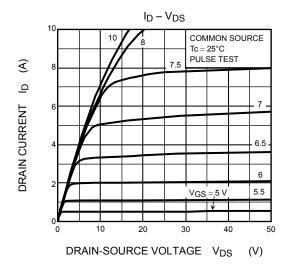
#### **Marking**

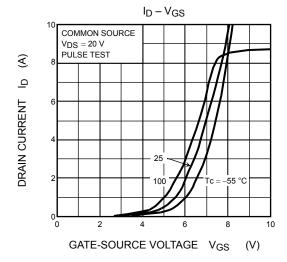


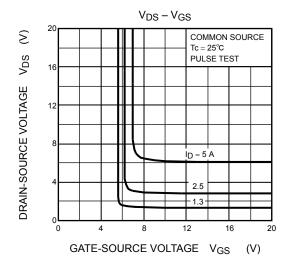
Note 4 : A line under a Lot No. identifies the indication of product Labels  $\hbox{[[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]}$ 

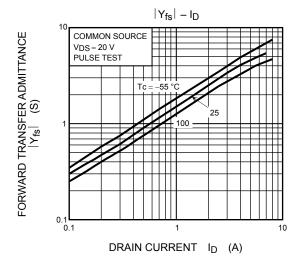
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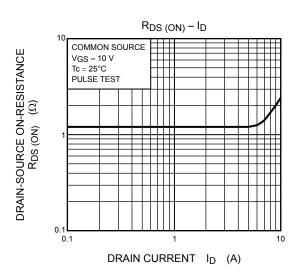




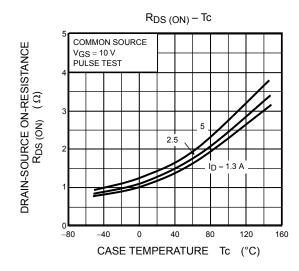


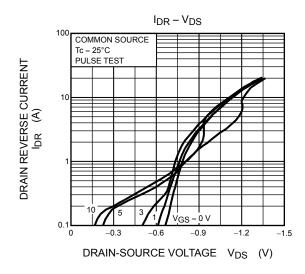


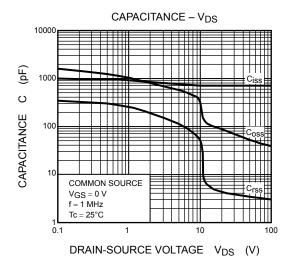


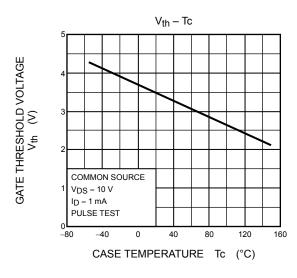


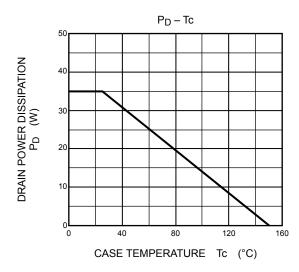
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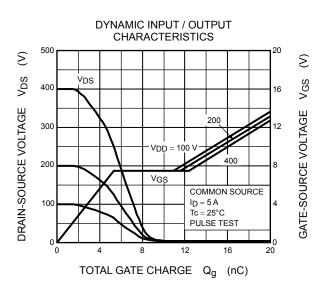


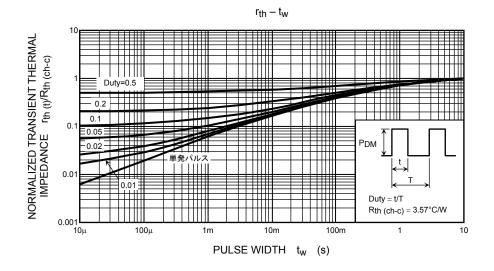


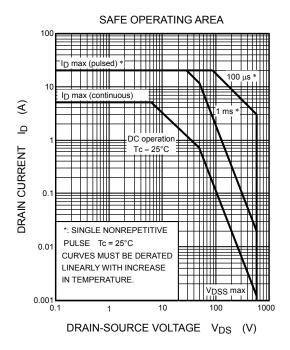


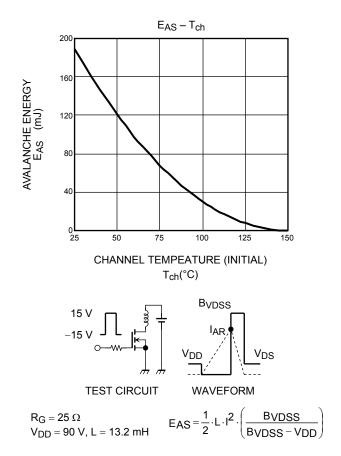












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